

### **INCHANGE SEMICONDUCTOR**

## isc N-Channel MOSFET Transistor

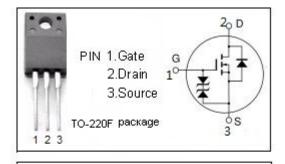
### 2SK2996

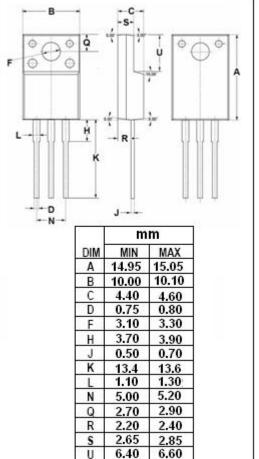
#### • FEATURES

- Drain Current  $I_D$ = 10A@ T<sub>C</sub>=25°C
- Drain Source Voltage-
  - : V<sub>DSS</sub>= 600V(Min)
- Low leakage current
- High forward transfer admittance
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATIONS

DC-DC converter, Relay Drive and motor Drive Application





#### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT					
V <sub>DSS</sub>	Drain-Source Voltage	600	V					
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V					
ID	Drain Current-Continuous	10	A					
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25°C	45	W					
Tj	Max. Operating Junction Temperature	150	°C					
T <sub>stg</sub>	Storage Temperature	-55~150	°C					
THERMAL CHARACTERISTICS								
SYMBOL	PARAMETER	MAX	UNIT					
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	2.78	°C/W					
R <sub>th j-a</sub>	Thermal Resistance, Junction to Ambient	62.5	°C/W					



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#### • ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> =10mA	600			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =1mA	2.0		4.0	V
VDSF	Forward voltage(Diode)	I <sub>DR</sub> = 10A ;V <sub>GS</sub> = 0			-1.7	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 5A			1.0	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±25V;V <sub>DS</sub> = 0			±10	uA
IDSS	Zero Gate Voltage Drain Current	V <sub>DS</sub> =600V; V <sub>GS</sub> = 0			100	μA



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